# NSN 5961-00-767-1009

Transistor - Page 1 of 1



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#### Inclosure Material:

Metal

**Overall Length:** 

0.340 inches

## **Overall Diameter:**

0.620 inches

## **Mounting Facility Quantity:**

2

### Internal Configuration:

Junction contact

### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-66

Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

120.0 breakdown voltage, collector-to-base, emitter open and 100.0 breakdown voltage, collector-to-emitter, base open and 6.0

breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

2.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

16.0 watts small-signal input power, common-collector absolute

#### **Special Features:**

Junction pattern arrangement: pnp

## Terminal Type And Quantity:

1 case and 2 pin

Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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